

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,547,909 B2
APPLICATION NO. : 10/597607
DATED : June 16, 2009
INVENTOR(S) : Joongseo Park

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title Page, Item (54) and Column 1, lines 1-3

Please delete “III_NITRIDE COMPOUND ICE SEMICONDUCTOR LIGHT EMITTING DEV” and insert --III-NITRIDE COMPOUND SEMICONDUCTOR LIGHT EMITTING DEVICE--

Title Page, Item (22)

Please delete “March 5, 2005” and insert --February 5, 2005--

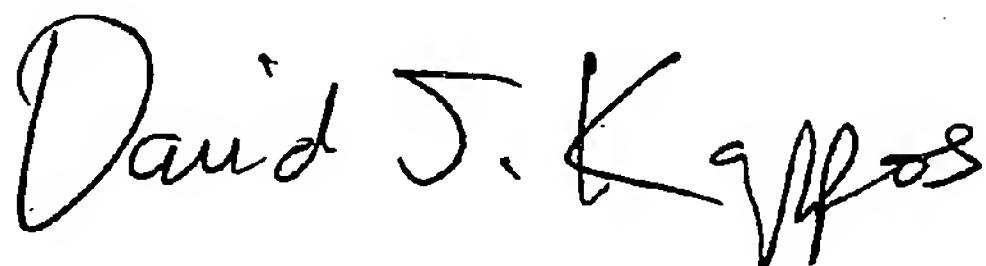
Title Page, Item (86)

For the filing or ‘371c’ date, delete “August 1, 2006” and insert --August 3, 2006--

This certificate supersedes the Certificate of Correction issued September 15, 2009.

Signed and Sealed this

Sixth Day of October, 2009



David J. Kappos
Director of the United States Patent and Trademark Office